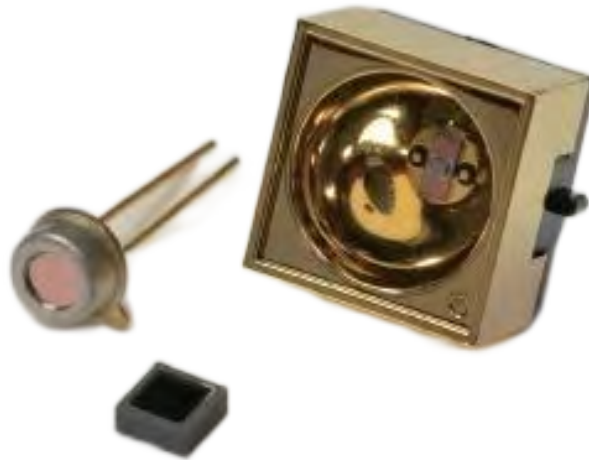


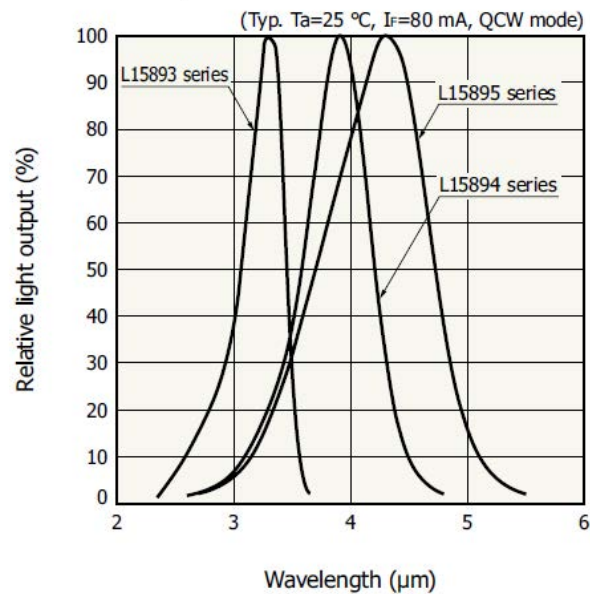
Mid-Infrared LEDs

3.3 to 4.3 μm



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■ Emission spectrum



Hamamatsu IR LED summary sheet

at room temp

valid

8/29/2024

subject to change without notice

wavelength, microns	part number (series-)	package (-suffix)	package type	window	IR Power out, quasi CW, min	\$ each, 1 to 25
3.3 μm	L15893-	-0330CA	ceramic surface mt	AR-Si	0.8 mW	\$36
		-0330CN	ceramic surface mt	none	0.8 mW	\$26
		-0330MA	TO-46	AR-Si	0.9 mW	\$112
		-0330ML	TO-46 with reflector	none	1.6 mW	\$125
3.9 μm	L15894-	-0390CA	ceramic surface mt	AR-Si	0.8 mW	\$36
		-0390CN	ceramic surface mt	none	0.8 mW	\$26
		-0390MA	TO-46		0.8 mW	\$112
		-0390ML	TO-46 with reflector	none	1.4 mW	\$125
4.3 μm	L15895-	-0430CA	ceramic surface mt	AR-Si	0.45 mW	\$36
		-0430CN	ceramic surface mt	none	0.45 mW	\$26
		-0430MA	TO-46	AR-Si	0.5 mW	\$112
		-0430ML	TO-46 with reflector	none	0.8 mW	\$125

Technical details of the above products follow this page

Please also see our catalog of

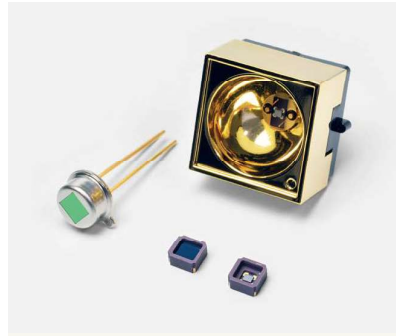
MINIATURE THERMAL INFRARED SOURCES

and our separate catalog of

CALIBRATION GRADE BLACKBODY SOURCES

Mid-infrared LED

L15893/L15894/L15895 series



Peak emission wavelength: 3.3 μm, 3.9 μm, 4.3 μm

The L15893 series, L15894 series, L15895 series are mid-infrared LEDs with the peak wavelength of 3.3 μm, 3.9 μm, and 4.3 μm respectively, manufactured using Hamamatsu unique crystal growth and process technologies. Output is significantly increased compared to the previous products. These are suitable as light sources mounted in gas detectors.

Features

- High output
- High-speed response
- High reliability
- Low power consumption
- Small surface mount type ceramic package
(L15893-0330CA/CN, L15894-0390CA/CN, L15895-0430CA/CN)
- TO-46 with reflector (for light condensing)
(L15893-0330ML, L15894-0390ML, L15895-0430ML)

Applications

- Gas detection (CH₄, CO₂)

Structure

Type no.	Package*1	Window material
L15893-0330CA NEW	Surface mount type ceramic	Si with AR coating
L15893-0330CN		None
L15893-0330MA	TO-46	Si with AR coating
L15893-0330ML	TO-46 with reflector	None*2
L15894-0390CA NEW	Surface mount type ceramic	Si with AR coating
L15894-0390CN		None
L15894-0390MA	TO-46	Si with AR coating
L15894-0390ML	TO-46 with reflector	None*2
L15895-0430CA NEW	Surface mount type ceramic	Si with AR coating
L15895-0430CN		None
L15895-0430MA	TO-46	Si with AR coating
L15895-0430ML	TO-46 with reflector	None*2

*1: These products are not hermetically sealed.

*2: To protect the emission section, a protective tape is applied to the surface of the product. Remove the tape after assembly.

▣ Absolute maximum ratings (Ta=25 °C, unless otherwise noted)

Type no.	Reverse voltage V _R (V)	Forward current I _F (mA)	Pulse forward current I _{FP} *3 (A)	Power dissipation P (mW)	Operating temperature T _{opr} *4 (°C)	Storage temperature T _{stg} *4 (°C)	Soldering temperature T _{sol} (°C)			
L15893-0330CA NEW	1	100	0.5	340	-40 to +85	-40 to +100	240 (twice)*5			
L15893-0330CN							-			
L15893-0330MA							-			
L15893-0330ML							-20 to +60	-20 to +60	-	
L15894-0390CA NEW							280	-40 to +85	-40 to +100	240 (twice)*5
L15894-0390CN										-
L15894-0390MA										-
L15894-0390ML								-20 to +60	-20 to +60	-
L15895-0430CA NEW							260	-40 to +85	-40 to +100	240 (twice)*5
L15895-0430CN										-
L15895-0430MA										-
L15895-0430ML									-20 to +60	-20 to +60

*3: Pulse width=10 μs, duty ratio=1%

*4: No dew condensation.

When there is a temperature difference between a product and the surrounding area in high humidity environments, dew condensation may occur on the product surface. Dew condensation on the product may cause deterioration in characteristics and reliability.

*5: Reflow soldering, JEDEC J-STD-020 MSL 3, see P.10

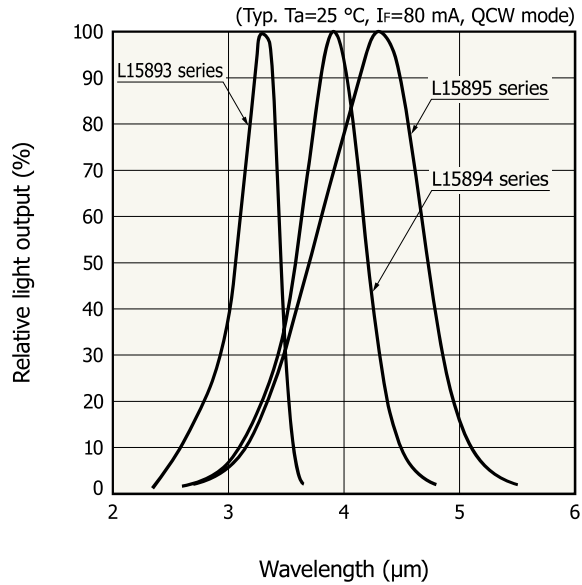
Note: Exceeding the absolute maximum ratings even momentarily may cause a drop in product quality. Always be sure to use the product within the absolute maximum ratings.

▣ Electrical and optical characteristics (Ta=25 °C)

Type no.	Peak emission wavelength λ _p *6			Spectral half width Δλ*6		Radiant flux φ _e *6		Forward voltage V _F *6		Rise time t _r 10 to 90%
	Min. (μm)	Typ. (μm)	Max. (μm)	Typ. (μm)	Max. (μm)	Min. (mW)	Typ. (mW)	Typ. (V)	Max. (V)	Max. (μs)
L15893-0330CA NEW	3.1	3.3	3.4	0.4	0.6	0.8	1.3	2.7	3.2	1
L15893-0330CN						0.9	1.5			
L15893-0330MA						1.6	2.6			
L15893-0330ML										
L15894-0390CA NEW	3.8	3.9	4.1	0.6	0.9	0.8	1.4	2.2	2.7	
L15894-0390CN						0.8	1.4			
L15894-0390MA						1.4	2.4			
L15894-0390ML										
L15895-0430CA NEW	4.1	4.3	4.4	1.0	1.3	0.45	0.75	2.0	2.5	
L15895-0430CN						0.5	0.8			
L15895-0430MA						0.8	1.4			
L15895-0430ML										

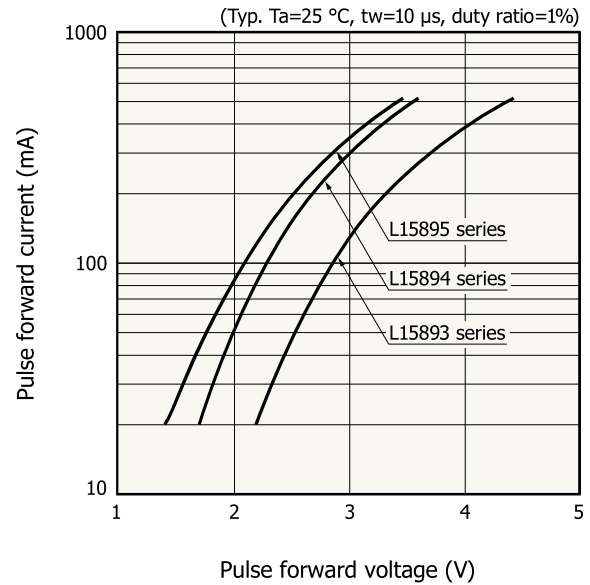
*6: I_F=80 mA, QCW (quasi continuous wave) mode (pulse width=100 μs, duty ratio=50%)

Emission spectrum



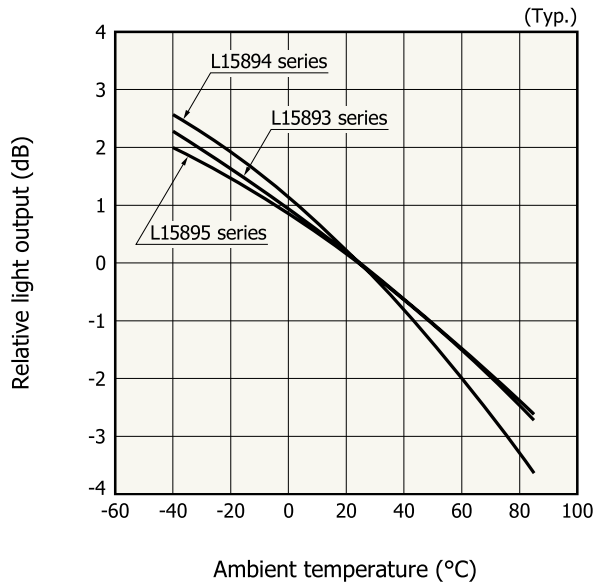
KLEDB0538EB

Pulse forward current vs. pulse forward voltage



KLEDB0542EB

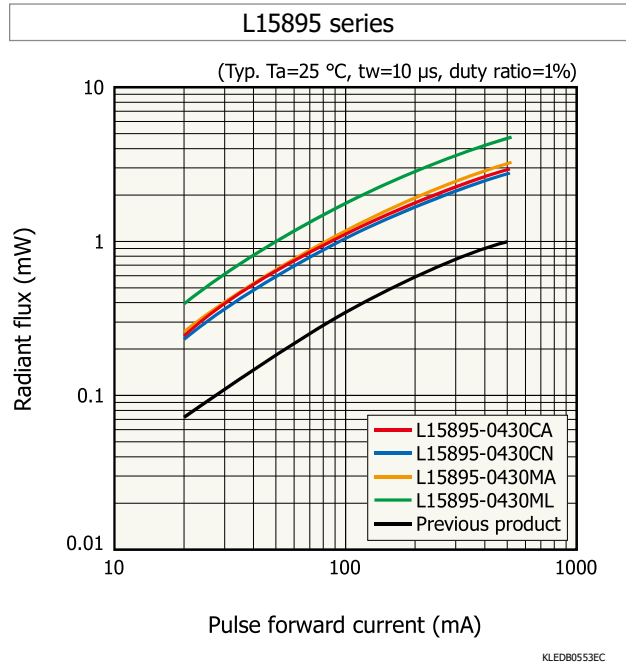
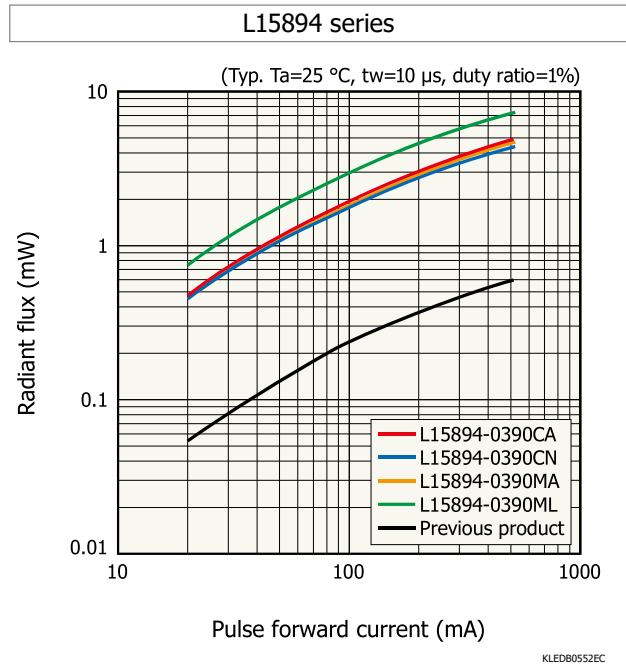
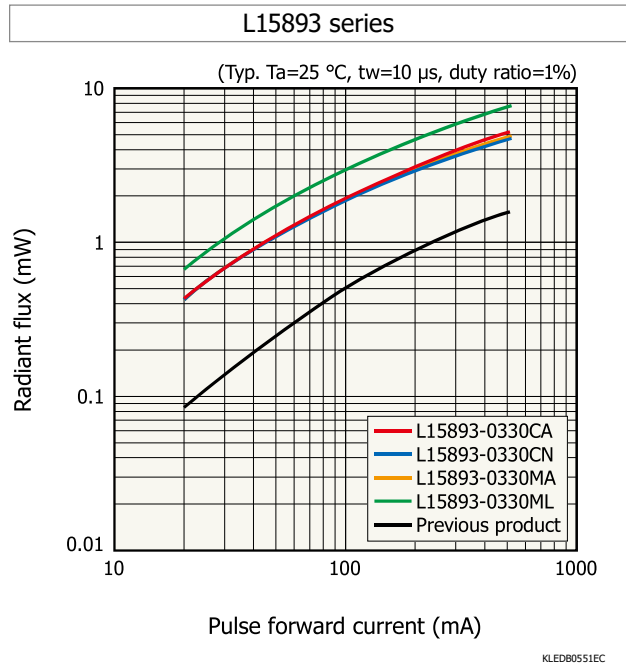
Light output vs. ambient temperature



L15893-0330ML, L15894-0390ML, L15895-0430ML:
operating temperature = $-20\text{ to }+60\text{ }^\circ\text{C}$

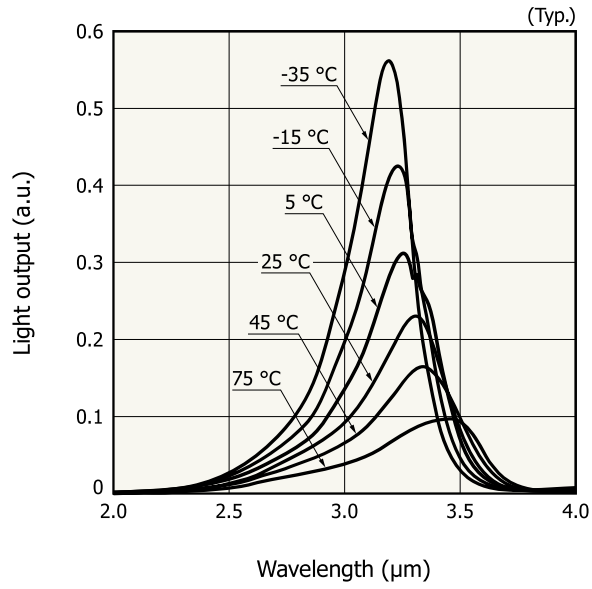
KLEDB0543EC

Radiant flux vs. pulse forward current

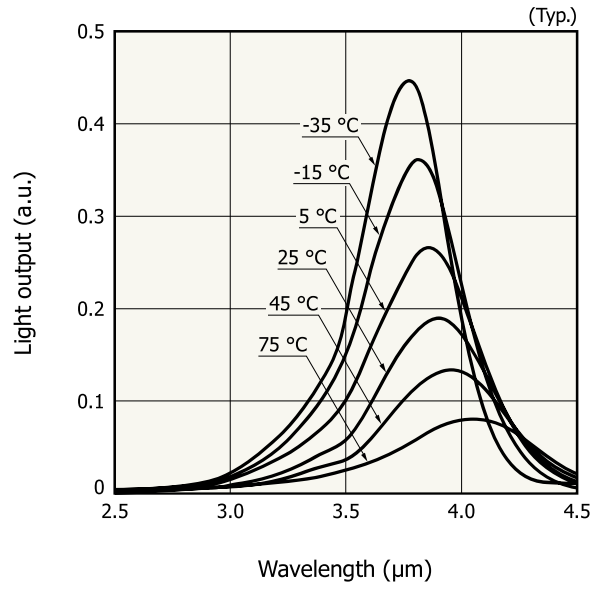


Temperature characteristics of emission spectrum

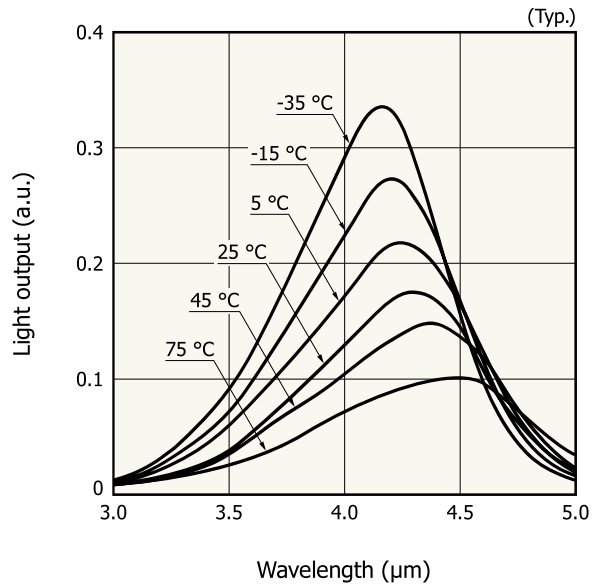
L15893 series



L15894 series



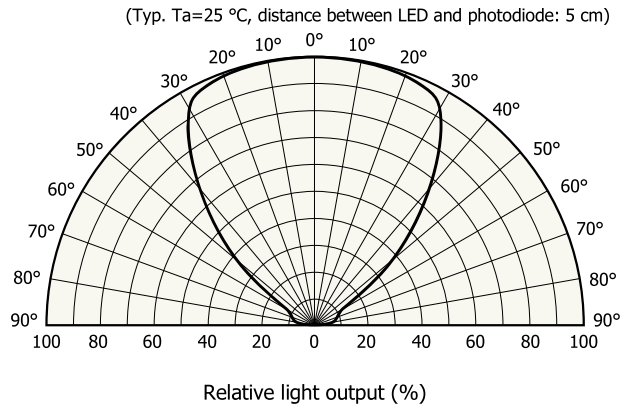
L15895 series



L15893-0330ML, L15894-0390ML, L15895-0430ML:
operating temperature = -20 to +60 °C

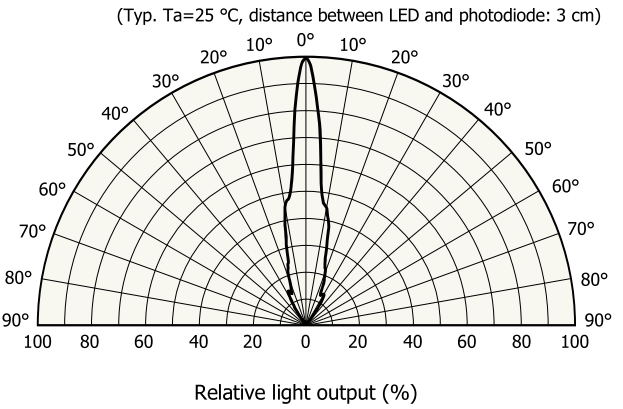
Directivity

L15893-0330CA/CN, L15894-0390CA/CN, L15895-0430CA/CN



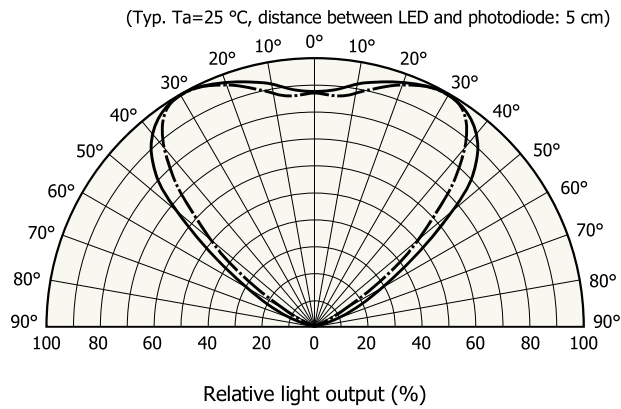
KLEDB0554EB

L15893-0330ML, L15894-0390ML, L15895-0430ML

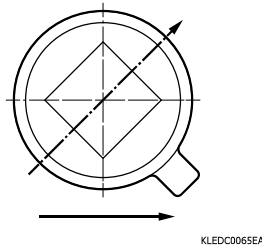


KLEDB0549EA

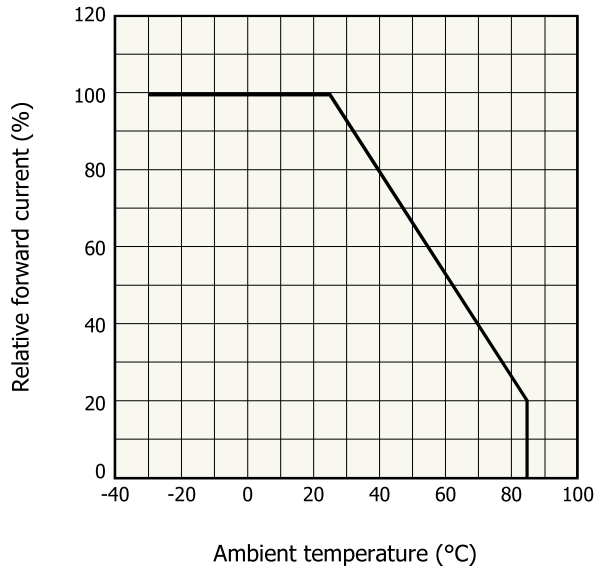
L15893-0330MA, L15894-0390MA, L15895-0430MA



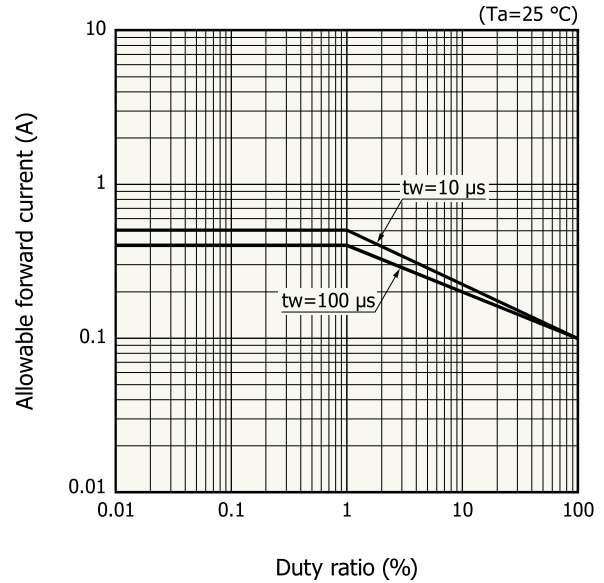
KLEDB0550EA



Allowable forward current vs. ambient temperature



Allowable forward current vs. duty ratio



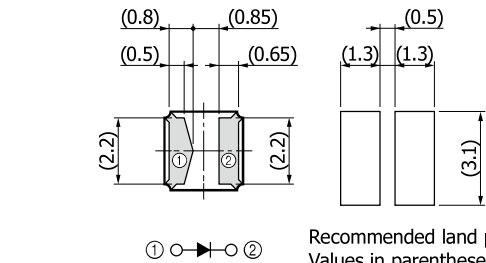
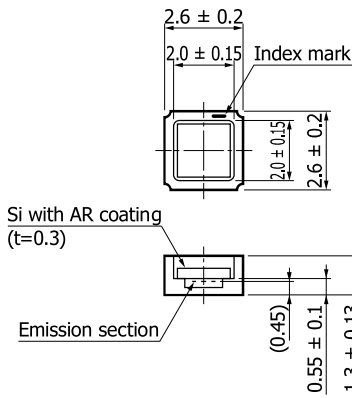
L15893-0330ML, L15894-0390ML, L15895-0430ML:
operating temperature = -20 to +60 °C

KLEDB0417EB

KLEDB0418EA

Dimensional outlines (unit: mm)

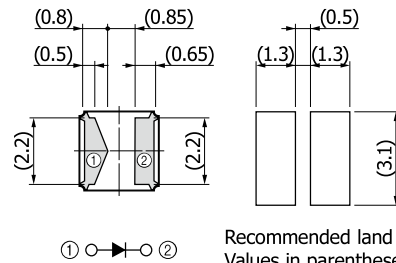
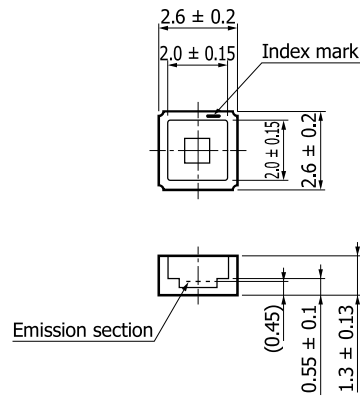
L15893-0330CA, L15894-0390CA, L15895-0430CA



Recommended land pattern
Values in parentheses
indicate reference values.

KLEDA0117EA

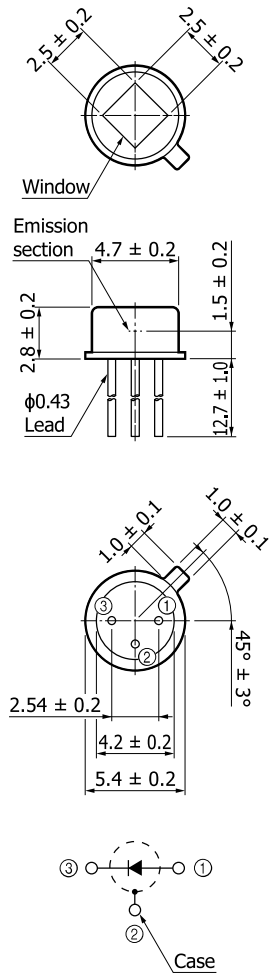
L15893-0330CN, L15894-0390CN, L15895-0430CN



Recommended land pattern
Values in parentheses
indicate reference values.

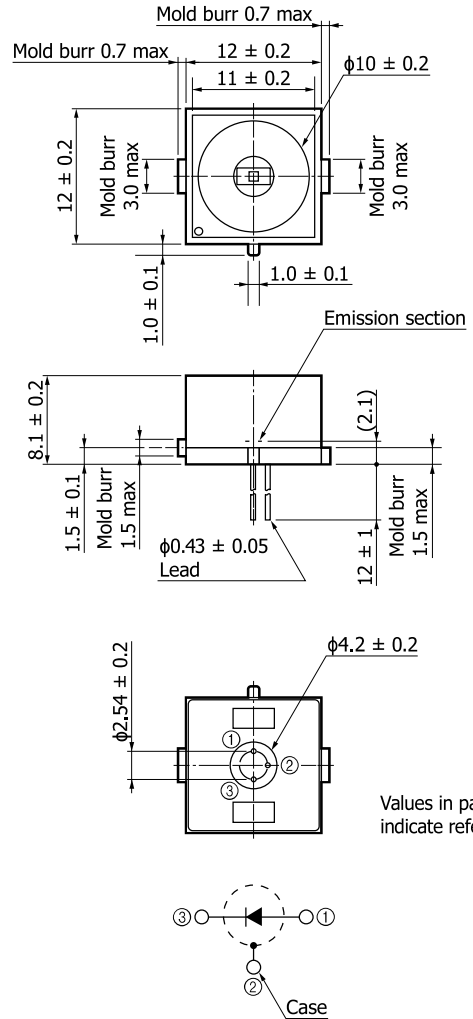
KLEDA0114EB

L15893-0330MA, L15894-0390MA, L15895-0430MA



KLEDA0113EA

L15893-0330ML, L15894-0390ML, L15895-0430ML



KLEDA0112EC

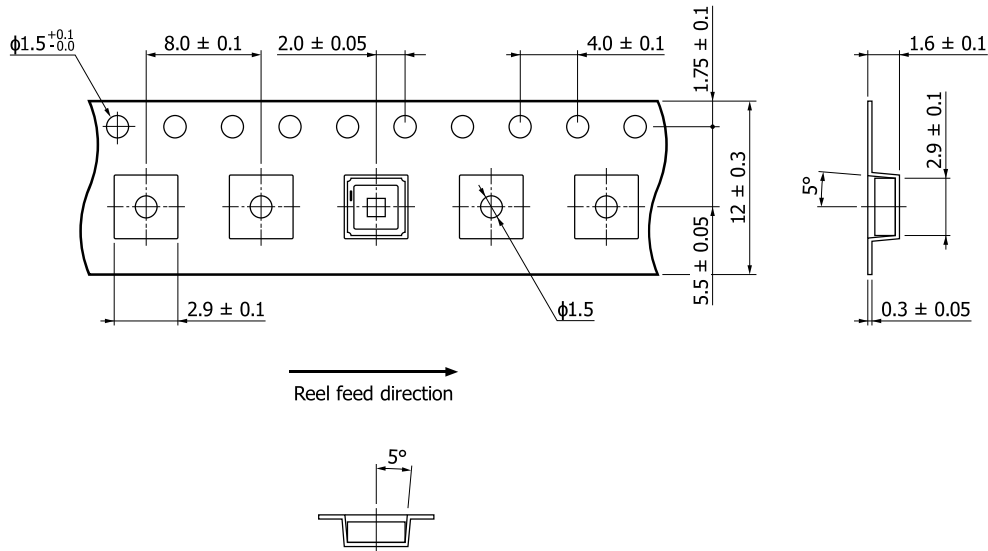
Standard packing specifications

L15893-0330CA/CN, L15894-0390CA/CN, L15895-0430CA/CN

- Reel (conforms to JEITA ET-7200)

Outer diameter	Hub diameter	Tape width	Material	Electrostatic characteristics
φ180 mm	φ60 mm	12 mm	PS	Conductive

- Embossed tape (unit: mm, material: PS, conductive)



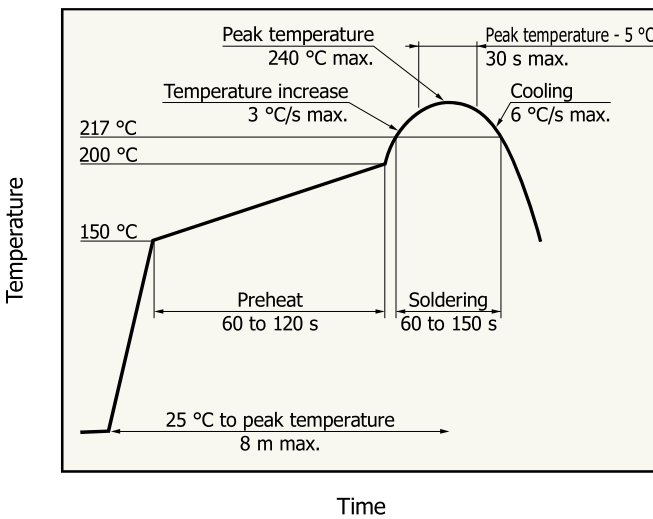
KLEDC0143EA

- Packing quantity
500 pcs/reel

- Packing state
Reel and desiccant in moisture-proof packaging (vacuum-sealed)

Recommended soldering conditions

L15893-0330CA/CN, L15894-0390CA/CN, L15895-0430CA/CN



KSPDB0418EA

- After unpacking, keep it in an environment at a temperature of 5 to 30 °C and a humidity of 60% or less, and perform soldering within 168 hours.
- The effect that the product receives during reflow soldering varies depending on the circuit board and reflow oven that are used. When you set reflow soldering conditions, check that problems do not occur in the product by testing out the conditions in advance.
- If three months have passed in an unpacked state or the above storage period has passed after opening, perform baking to dehumidify before reflow soldering. For the baking, refer to the precautions "Surface mount type products." When you set baking conditions, check that problems do not occur in the product by testing out the conditions in advance.

L15893-0330MA, L15894-0390MA, L15895-0430MA

Solder temperature: 260 °C (5 s or less, once)

Solder the leads at a point at least 2 mm away from the package body.

L15893-0330ML, L15894-0390ML, L15895-0430ML

Solder temperature: 230 °C (5 s or less, once)

Solder the leads at a point at least 2 mm away from the package body.

Note: When you set soldering conditions, check that problems do not occur in the product by testing out the conditions in advance.

Related products

Evaluation kit M16953 for InAsSb photovoltaic detector



The M16953 is an evaluation amplifier for gas measurement used in combination with Hamamatsu's InAsSb photovoltaic devices with band-pass filters (TO-46 package). These can detect infrared light transmitted through a band-pass filter simply by connecting a power supply ± 2.5 V.

Specifications

- **Applicable devices: InAsSb photovoltaic detectors with band-pass filter***⁷
- **Gain: 10^7 V/A**
- **Frequency characteristics: DC to 80 kHz**
- **Recommended drive voltage: ± 2.5 V**

*7: InAsSb photovoltaic devices with band-pass filter sold separately

Evaluation kit M16615 for mid infrared LED



The M16615 is a driver for mid infrared LED (TO-46 package). The LED can be pulse-driven simply by connecting a power supply (+15 V). This is used in combination with the evaluation kit M16953 series for InAsSb photovoltaic detector.

Specifications

- **Applicable devices: Mid infrared LED***⁸
- **Output current: 400 mA**
- **Output pulse: 10 μ s**
- **Output cycle: 1000 μ s**
- **Recommended drive voltage: +15 V**

*8: Mid infrared LED sold separately

■ Related information

www.hamamatsu.com/sp/ssd/doc_en.html

- Precautions
 - Disclaimer
 - Safety consideration
 - Metal, ceramic, plastic package products
 - Surface mount type products
 - Compound opto-semiconductors (photosensors, light emitters)
- Technical note
 - LED

Information described in this material is current as of July 2024.

Product specifications are subject to change without prior notice due to improvements or other reasons. This document has been carefully prepared and the information contained is believed to be accurate. In rare cases, however, there may be inaccuracies such as text errors. Before using these products, always contact us for the delivery specification sheet to check the latest specifications.

The product warranty is valid for one year after delivery and is limited to product repair or replacement for defects discovered and reported to us within that one year period. However, even if within the warranty period we accept absolutely no liability for any loss caused by natural disasters or improper product use. Copying or reprinting the contents described in this material in whole or in part is prohibited without our prior permission.

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